





20V N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} | I _D T _A = +25°C (Note 5) |
|----------------------|--------------------------------|--|
| 20V | 175mΩ @ $V_{GS} = 4.5V$ | 1.30A |
| | 240mΩ @ $V_{GS} = 2.5V$ | 1.11A |
| | 360mΩ @ V _{GS} = 1.8V | 0.91A |
| | 500mΩ @ V _{GS} = 1.5V | 0.82A |

Description

This MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

Load switch

Features

- Footprint of just 0.6mm² thirteen times smaller than SOT23
- 0.4mm profile ideal for low profile applications
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate 2KV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

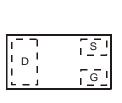
- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.001 grams (approximate)



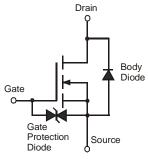




Bottom View



Top View Internal Schematic



Equivalent Circuit

Ordering Information (Note 4)

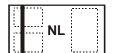
| Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|----------------|---------|--------------------|-----------------|-------------------|
| DMN2300UFB4-7B | NL | 7 | 8 | 10,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information

DMN2300UFB4-7B



Top View Bar Denotes Gate and Source Side

NL = Product Type Marking Code





Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

| Characteri | stic | | Symbol | Value | Unit |
|---|------|----------------|------------------|-------|------|
| Drain-Source Voltage | | | V_{DSS} | 20 | V |
| Gate-Source Voltage | | | V _{GSS} | ±8 | V |
| Continuous Drain Current (Note 5) Steady $T_A = +25^{\circ}C$ State $T_A = +85^{\circ}C$ | | I _D | 1.30 0.96 | А | |
| Pulsed Drain Current (Note 6) | | | I _{DM} | 6 | А |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P_{D} | 500 | mW |
| Thermal Resistance, Junction to Ambient @T _A = +25°C | R _{0JA} | 250 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

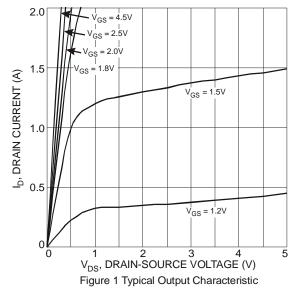
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

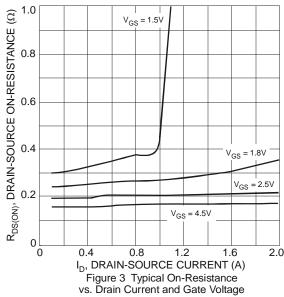
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|----------------------|------|------|------|------|---|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 20 | _ | _ | V | $V_{GS} = 0V, I_{D} = 10\mu A$ | |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | _ | _ | 1 | μA | $V_{DS} = 20V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | _ | _ | 10 | μA | $V_{GS} = \pm 8V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 0.45 | _ | 0.95 | V | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | |
| | | _ | _ | 175 | | $V_{GS} = 4.5V, I_D = 1A$ | |
| Static Drain-Source On-Resistance | | _ | _ | 240 | 0 | $V_{GS} = 2.5V, I_D = 750mA$ | |
| Static Drain-Source On-Resistance | R _{DS (ON)} | _ | _ | 360 | mΩ | $V_{GS} = 1.8V, I_D = 500mA$ | |
| | | _ | _ | 500 | | V _{GS} = 1.5V, I _D = 200mA | |
| Forward Transfer Admittance | Y _{fs} | 40 | _ | _ | mS | $V_{DS} = 3V, I_{D} = 30mA$ | |
| Diode Forward Voltage | V _{SD} | _ | 0.7 | 1.2 | V | $V_{GS} = 0V, I_{S} = 300mA$ | |
| DYNAMIC CHARACTERISTICS | | | | | - | | |
| Input Capacitance | C _{iss} | _ | 64.3 | _ | pF | | |
| Output Capacitance | Coss | _ | 6.1 | _ | pF | $V_{DS} = 25V, V_{GS} = 0V,$ -f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{rss} | _ | 4.5 | _ | pF | TI = 1.0IVID2 | |
| Gate Resistance | Rg | _ | 70 | _ | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ | |
| Total Gate Charge | Qg | _ | 1.6 | _ | nC | V _{GS} = 4.5V, V _{DS} = 15V, I _D = 1A | |
| Gate-Source Charge | Q _{gs} | _ | 0.2 | _ | nC | | |
| Gate-Drain Charge | Q_{gd} | _ | 0.2 | _ | nC | | |
| Turn-On Delay Time | t _{D(on)} | _ | 3.5 | _ | ns | | |
| Turn-On Rise Time | tr | _ | 2.8 | _ | ns | V _{DS} = 10V, I _D = 1A | |
| Turn-Off Delay Time | t _{D(off)} | _ | 38 | _ | ns | $V_{GS} = 10V$, $R_G = 6\Omega$ | |
| Turn-Off Fall Time | t _f | _ | 13 | _ | ns | 1 | |

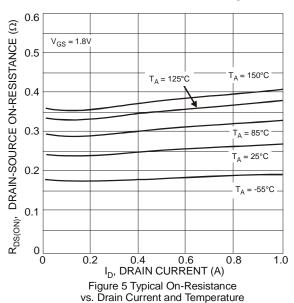
Notes:

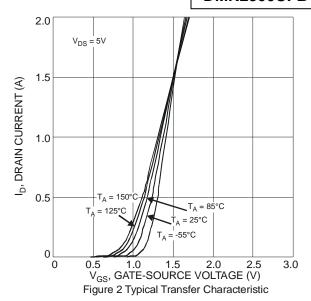
- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
- 6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.
 7. Short duration pulse test used to minimize self-heating effect.

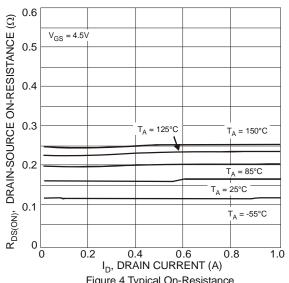


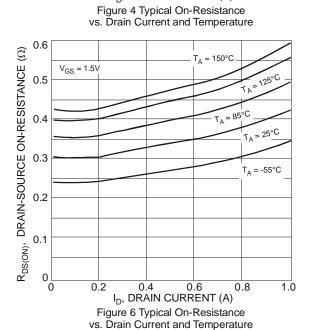














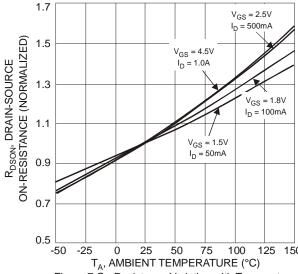


Figure 7 On-Resistance Variation with Temperature

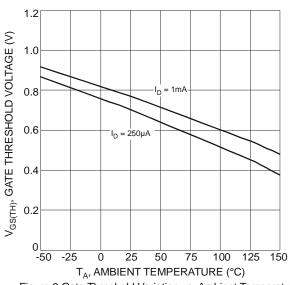
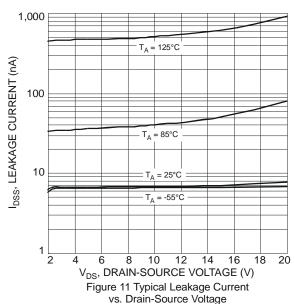


Figure 9 Gate Threshold Variation vs. Ambient Temperature



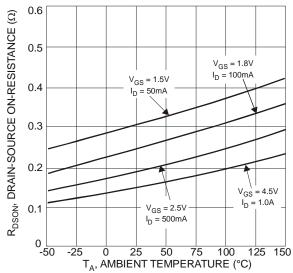
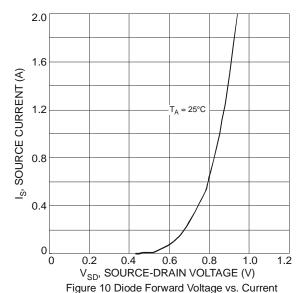


Figure 8 On-Resistance Variation with Temperature



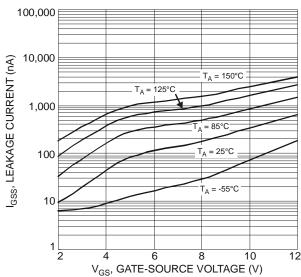


Figure 12 Leakage Current vs. Gate-Source Voltage



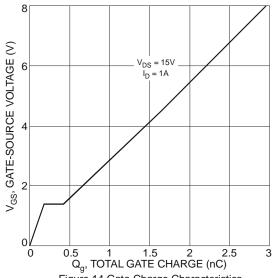


Figure 14 Gate-Charge Characteristics

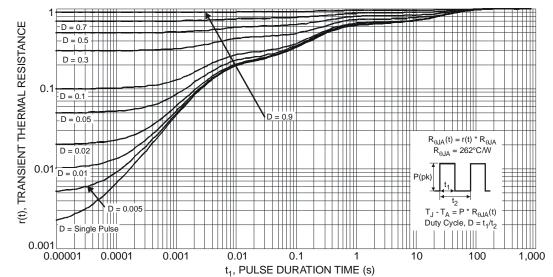


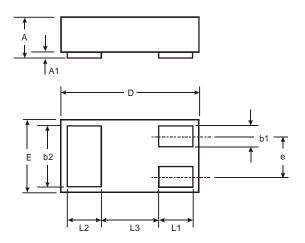
Figure 15 Transient Thermal Response





Package Outline Dimensions

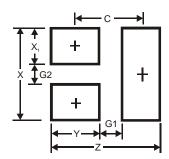
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| X2-DFN1006-3 | | | | | |
|----------------------|------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | | 0.40 | _ | | |
| A1 | 0 | 0.05 | 0.03 | | |
| b1 | 0.10 | 0.20 | 0.15 | | |
| b2 | 0.45 | 0.55 | 0.50 | | |
| D | 0.95 | 1.05 | 1.00 | | |
| Е | 0.55 | 0.65 | 0.60 | | |
| е | | _ | 0.35 | | |
| L1 | 0.20 | 0.30 | 0.25 | | |
| L2 | 0.20 | 0.30 | 0.25 | | |
| L3 | _ | _ | 0.40 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) | | |
|------------|---------------|--|--|
| Z | 1.1 | | |
| G1 | 0.3 | | |
| G2 | 0.2 | | |
| Х | 0.7 | | |
| X1 | 0.25 | | |
| Y | 0.4 | | |
| С | 0.7 | | |





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